SIEMENS

product brand name

Data sheet 3UG4841-2CA40

SIRIUS



Digital monitoring relay cos phi and current monitoring for IO-Link 90...690 V AC, 0.2...10 A 0vershoot and undershoot ON-delay time Tripping delay time Hysteresis 0.1 to 3.0 A 2 change-over contacts, spring-type connection system

product brand name	SIRIUS
product designation	Cos phi monitoring relay with digital setting
product type designation	3UG4
General technical data	
product function	Active power monitoring relay
design of the display	LCD
insulation voltage for overvoltage category III according to IEC 60664	
with degree of pollution 2 rated value	690 V
degree of pollution	2
surge voltage resistance rated value	6 kV
protection class IP	IP20
shock resistance according to IEC 60068-2-27	sinusoidal half-wave 15g / 11 ms
mechanical service life (operating cycles) typical	10 000 002
electrical endurance (operating cycles) at AC-15 at 230 V typical	100 000
thermal current of the switching element with contacts maximum	5 A
reference code according to IEC 81346-2	K
relative repeat accuracy	1 %
Substance Prohibitance (Date)	05/01/2012
SVHC substance name	Blei - 7439-92-1 Bleimonoxid (Bleioxid) - 1317-36-8 Dicyclohexylphthalat (DCHP) - 84-61-7
Product Function	
product function	
 overcurrent detection 1 phase 	Yes
 undercurrent detection 1 phase 	Yes
 adjustable open/closed-circuit current principle 	Yes
external reset	Yes
Control circuit/ Control	
type of voltage of the control supply voltage	DC
control supply voltage at AC	
• at 50 Hz rated value	0 0 V
at 60 Hz rated value	0 0 V
control supply voltage at DC	
rated value	24 24 V
supply voltage frequency for auxiliary and control circuit rated value	0 0 Hz
operating range factor control supply voltage rated value at	
DC	
DC ■ initial value	0.75

full-scale value	1.25
Supply voltage	1.20
supply voltage supply voltage frequency rated value	60 Hz
,	00 HZ
Measuring circuit	40
type of current for monitoring	AC
measurable current	0.2 10 A
adjustable current response value current	0.0 40.4
• 1	0.2 10 A
• 2	0.2 10 A
adjustable response delay time	0.0000
when starting	0 999.9 s
with lower or upper limit violation	0 999.9 s
adjustable switching hysteresis for measured current value	0 3 000 mA
accuracy of digital display	+/-1 digit
Precision	40.07
relative metering precision	10 %
Communication/ Protocol	
protocol is supported IO-Link protocol	Yes
IO-Link transfer rate	COM2 (38,4 kBaud)
point-to-point cycle time between master and IO-Link device minimum	10 ms
type of voltage supply via input/output link master	Yes
data volume	
of the address range of the inputs with cyclical transfer	4 byte
total	. 5,10
of the address range of the outputs with cyclical transfer	2 byte
total	
Auxiliary circuit	
control supply voltage rated value	30 18
number of NC contacts delayed switching	0
number of NO contacts delayed switching	0
number of CO contacts delayed switching	2
operating frequency with 3RT2 contactor maximum	5 000 1/h
Main circuit	
number of poles for main current circuit	1
operating voltage rated value	90 690 V
ampacity of the output relay at AC-15	
• at 250 V at 50/60 Hz	3 A
• at 400 V at 50/60 Hz	3 A
ampacity of the output relay at DC-13	
• at 24 V	1 A
at 24 Vat 125 V	0.2 A
at 24 Vat 125 Vat 250 V	0.2 A 0.1 A
 at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode	0.2 A 0.1 A 200 mA
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum	0.2 A 0.1 A 200 mA 10 mA
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output	0.2 A 0.1 A 200 mA
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay	0.2 A 0.1 A 200 mA 10 mA
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility	0.2 A 0.1 A 200 mA 10 mA
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference	0.2 A 0.1 A 200 mA 10 mA 4 A
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4	0.2 A 0.1 A 200 mA 10 mA 4 A
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4	0.2 A 0.1 A 200 mA 10 mA 4 A
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Galvanic isolation	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Galvanic isolation galvanic isolation	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV 10 V/m 6 kV contact discharge / 8 kV air discharge
at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Galvanic isolation galvanic isolation • between input and output	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV 10 V/m 6 kV contact discharge / 8 kV air discharge
 at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Galvanic isolation between input and output between the outputs 	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV 10 V/m 6 kV contact discharge / 8 kV air discharge
 at 24 V at 125 V at 250 V ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Calvanic isolation between input and output between the outputs between the voltage supply and other circuits 	0.2 A 0.1 A 200 mA 10 mA 4 A 2 kV 2 kV 1 kV 10 V/m 6 kV contact discharge / 8 kV air discharge

control circuit	
	anring leaded terminals
type of electrical connection	spring-loaded terminals
type of connectable conductor cross-sections	24 (0.05 4.5 mass2)
• solid	2x (0.25 1.5 mm²)
finely stranded with core end processing	2 x (0.25 1.5 mm²)
finely stranded without core end processing	2x (0.25 1.5 mm²)
• for AWC cables solid	2x (24 16)
• for AWG cables stranded	2x (24 16)
connectable conductor cross-section	0.05 4.5
• solid	0.25 1.5 mm²
finely stranded with core end processing	0.25 1.5 mm²
finely stranded without core end processing	0.25 1.5 mm²
AWG number as coded connectable conductor cross section	
• solid	24 16
• stranded	20 14
Installation/ mounting/ dimensions	
mounting position	any
fastening method	snap-on mounting
height	103 mm
width	22.5 mm
depth	91 mm
required spacing	
with side-by-side mounting	
— forwards	0 mm
— backwards	0 mm
— upwards	0 mm
— downwards	0 mm
— at the side	0 mm
for grounded parts	
— forwards	0 mm
— backwards	0 mm
— upwards	0 mm
— at the side	0 mm
— downwards	0 mm
• for live parts	
— forwards	0 mm
— backwards	0 mm
— upwards	0 mm
— downwards	0 mm
— at the side	0 mm
Ambient conditions	
installation altitude at height above sea level maximum	2 000 m
ambient temperature	
during operation	-25 +60 °C
during storage	-40 +85 °C
during transport	-40 +85 °C
Approvals Certificates	
General Product Approval	





Confirmation



Manufacturer Declaration



General Product Approval	Test Certificates	Marine / Shipping	other	
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Railway

Vibration and Shock

Further information

Siemens has decided to exit the Russian market (see here).

https://press.siemens.com/global/en/pressrelease/siemens-wind-down-russian-business

Siemens is working on the renewal of the current EAC certificates.

Please contact your local Siemens office on the status of validity of the EAC certification if you intend to import or offer to supply these products to an EAC relevant market (other than the sanctioned EAEU member states Russia or Belarus).

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3UG4841-2CA40

Cax online generator

http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en&mlfb=3UG4841-2CA40

Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

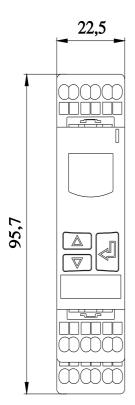
https://support.industry.siemens.com/cs/ww/en/ps/3UG4841-2CA40

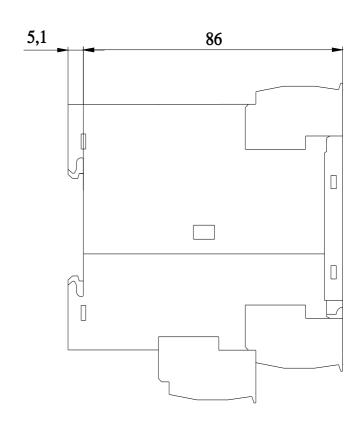
Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

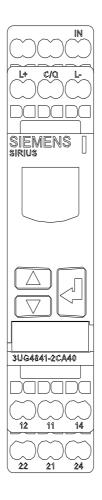
http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3UG4841-2CA40&lang=en

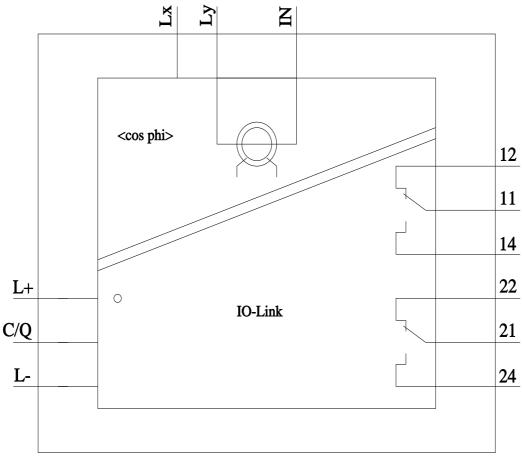
Characteristic: Derating

https://support.industry.siemens.com/cs/ww/en/ps/3UG4841-2CA40/manual









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